	Search Text	DBs
1	("6384461").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
2	"6384461".URPN.	USPAT
3	("5574292" "5616524").PN.	USPAT
4	first with ((silicon near (oxynitride oxy near nitride) "siO.sub.xN.sub.y" "si O.sub.y N.sub.y" "si O.sub.y N.sub.x") (benzocyclobutene benzo near cyclo near butene benzo near cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second with ((oxide dioxide di near oxide))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
5	F	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

Search Text	DBs
n massivaringi wirn (loyide dioyide di	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDE

	Search Text	DBs
7	(((first near2 (dielectric passivation insulating insulation passivating) with ((silicon near (oxynitride oxy near nitride) "siO.sub.xN.sub.y" "si O.sub.x N.sub.y" "si O.sub.y N.sub.x" "siO.sub.yN.sub.x") (benzocyclobutene benzo near cyclo near butene benzo near cyclo near butene benzo near cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second near2 (dielectric passivation insulating insulation passivating) with ((oxide dioxide di near oxide))) and (first with ((silicon near (oxynitride oxy near nitride) "siO.sub.xN.sub.y" "si O.sub.y N.sub.x" "siO.sub.y N.sub.x" (benzocyclobutene benzo near cyclo near butene benzo near cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second with ((oxide dioxide di near oxide)))) and ("438"/\$6 "257"/\$6)) and ("a" amorphous) near (silicon si)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
8	mushroom near (shape shaped) near2 electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
9	mear burene benzo bear cycloburene	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Search Text	DBs
10	((first near2 (dielectric passivation insulating insulation passivating) with ((silicon near (oxynitride oxy near nitride) "siO.sub.xN.sub.y" "si O.sub.x N.sub.y" "si O.sub.x N.sub.y" "si O.sub.y N.sub.x" "siO.sub.yN.sub.x") (benzocyclobutene benzo near cyclo near butene benzo near cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second near2 (dielectric passivation insulating insulation passivating) with ((oxide dioxide di near oxide))) and (first with ((silicon near (oxynitride oxy near nitride) "siO.sub.xN.sub.y" "si O.sub.y N.sub.x" "siO.sub.y N.sub.x" "siO.sub.y N.sub.x") (benzocyclobutene benzo near cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second with ((oxide dioxide di near oxide)))) and 257/458	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDE

	Search Text	DBs
11	<u> </u>	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
12		US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Search Text	DBs
13	(first with ((silicon near (oxynitride oxy near nitride) "si0.sub.xN.sub.y" "si 0.sub.y N.sub.y" "si 0.sub.y N.sub.x") (benzocyclobutene benzo near cyclo near butene benzo near cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second with ((oxide dioxide di near oxide))) and lateral\$2 with leak\$3 with current	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
14	(first with ((silicon near (oxynitride oxy near nitride) "si0.sub.xN.sub.y" "si 0.sub.y N.sub.x" "si 0.sub.y N.sub.x" "si0.sub.yN.sub.x") (benzocyclobutene benzo near cyclo near butene benzo near cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second with ((oxide dioxide di near oxide))) and leak\$3 with current	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

Search Text	DBs
((first near2 (dielectric passivation insulating insulation passivating) with ((silicon near (oxynitride oxy near nitride) "siO.sub.xN.sub.y" "si O.sub.x N.sub.y" "si O.sub.y N.sub.x" "siO.sub.yN.sub.x") (benzocyclobutene benzo near cyclo near butene benzo near cyclo near butene benzo near cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second near2 (dielectric passivation insulating insulation passivating) with ((oxide dioxide di near oxide))) and (first with ((silicon near (oxynitride oxy near nitride) "siO.sub.xN.sub.y" "si O.sub.y N.sub.x" "siO.sub.yN.sub.x") (benzocyclobutene benzo near cyclobutene benzocyclo near butene benzo near cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second with ((oxide dioxide di near oxide)))) and ("438"/\$6 "257"/\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Search Text	DBs
16	first with ((silicon near (oxynitride oxy near nitride) "siO.sub.xN.sub.y" "si O.sub.x N.sub.y" "si O.sub.y N.sub.x" "siO.sub.yN.sub.x") (benzocyclobutene benzo near cyclo near butene benzo near cyclobutene benzocyclo near butene BCB) (polyamide poly near amide)) and second with ((oxide dioxide di near oxide)) and ("438"/\$6 "257"/\$6) not (((first near2 (dielectric passivation insulating insulation passivating) with ((silicon near (oxynitride oxy near nitride) "siO.sub.xN.sub.y" "si O.sub.x" "siO.sub.y N.sub.x"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
17	IN SIID V" "SI () SIID V N SIID X"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
18	("4700457" "4985718" "4990463"	USPAT.

	Search Text	DBs
19	("5232970" "5288989" "5416233").PN.	USPAT
20	("4577395" "4833094" "5026659" "5162248" "5270241" "5275974" "5292679" "5384152" "5604696").PN.	USPAT
Z 1	full near fill near factor near image near array	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
ZZ	full near fill near factor near image near array	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
23	fill near factor near imag\$3 near array	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
24	fill near factor near image near array	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
25	fill near2 factor near imag\$3 near array	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
26	imag\$3 near array	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
27	(imag\$3 near array) and upper near electrode with (ito (tin indium) near2 oxide) with pattern\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
28	<pre>(imag\$3 near array) and electrode with (ito (tin indium) near2 oxide) with pattern\$3</pre>	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
1	<pre>((imag\$3 near array) and electrode with (ito (tin indium) near2 oxide) with pattern\$3) not ((imag\$3 near array) and upper near electrode with (ito (tin indium) near2 oxide) with pattern\$3)</pre>	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
30	(438/38,622,624,637,778,786,787,958,98 1,for.395,for.489,for.493).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
31	<pre>imag\$3 near array and ((438/38,622,624,637,778,786,787,958,9 81,for.395,for.489,for.493).CCLS.)</pre>	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
32	second adj passivation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Search Text	DBs
33	imag\$3 near array and ((438/38,622,624,637,778,786,787,958,981,for.395,for.489,for.493).CCLS.) and @pd>="20030221"	
34	("20020089026").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
35	imag\$3 near array and ((438/38,622,624,637,778,786,787,958,981,for.395,for.489,for.493).CCLS.) and @pd>="20030820"	
36	("20020089026").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
37	"5858832".URPN.	USPAT
38	("4700457" "4985718" "4990463" "5006481" "5262354" "5312512").PN.	USPAT
39	("5499207").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
40	"5499207".URPN.	USPAT
41	("5155573" "5321649" "5382817").PN.	USPAT
42	jp-62293726-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
43	"5712506".URPN.	USPAT
44	("5232970" "5288989" "5416233").PN.	USPAT
45	"5288989".URPN.	USPAT
46	("4780394" "5233181" "5243177").PN.	USPAT
47	bcb adj dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
48	imag\$3 near array and ((438/38,622,624,637,778,786,787,958,981,for.395,for.489,for.493).CCLS.) and @pd>="20010225"	
149	bcb adj dielectric and (oxy near nitride oxynitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Search Text	DBs
	- 1, -	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
51	imag\$3 near array and ((438/38,622,624,637,778,786,787,958,981,for.395,for.489,for.493).CCLS.) and @pd>="20040813"	